



2SB919/2SD1235

30V/8A High-Speed Switching Applications

Applications

- Large current switching of relay drivers, high-speed inverters, converters.

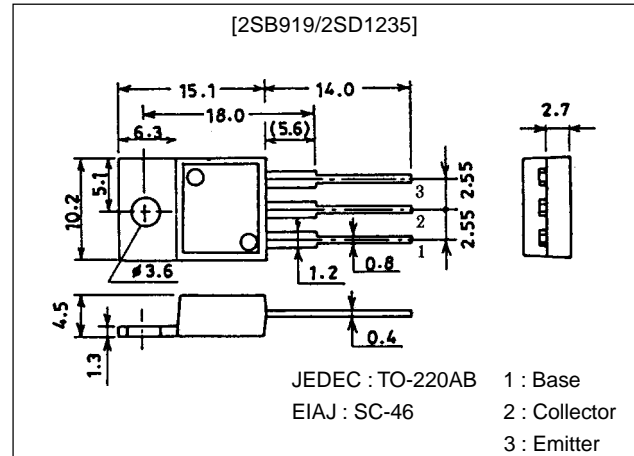
Features

- Low collector-to-emitter saturation voltage : $V_{CE(sat)} = -0.5V$ (PNP), $0.4V$ (NPN) max.
- Large current capacity.

Package Dimensions

unit:mm

2010C



() : 2SB919

Specifications

Absolute Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V_{CBO}		(-) 60	V
Collector-to-Emitter Voltage	V_{CEO}		(-) 30	V
Emitter-to-Base Voltage	V_{EBO}		(-) 6	V
Collector Current	I_C		(-) 8	A
Collector Current (Pulse)	I_{CP}		(-) 15	A
Collector Dissipation	P_C		1.75	W
		$T_c=25^\circ\text{C}$	30	W
Junction Temperature	T_J		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to $+150$	$^\circ\text{C}$

Electrical Characteristics at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	I_{CBO}	$V_{CB} = (-)40V, I_E = 0$			(-) 0.1	mA
Emitter Cutoff Current	I_{EBO}	$V_{EB} = (-)4V, I_C = 0$			(-) 0.1	mA
DC Current Gain	h_{FE1}	$V_{CE} = (-)2V, I_C = (-)1A$	70^*		280^*	
	h_{FE2}	$V_{CE} = (-)2V, I_C = (-)4A$	30			
Gain-Bandwidth Product	f_T	$V_{CE} = (-)5V, I_C = (-)1A$		120		MHz

* : The 2SB919/2SD1235 are classified as follows according to h_{FE} at 1A.

70	Q	140	100	R	200	140	S	280
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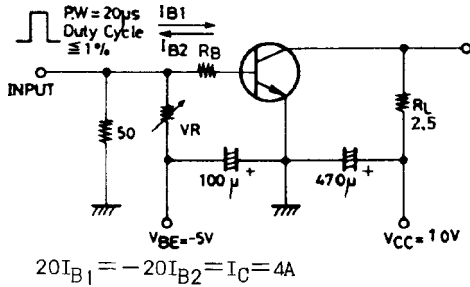
TOKYO OFFICE Tokyo Bldg., 1-10, 1 Chome, Ueno, Taito-ku, TOKYO, 110-8534 JAPAN

92098HA (KT)/D251MH/4067KI/D152KI, TS No.1046-1/4

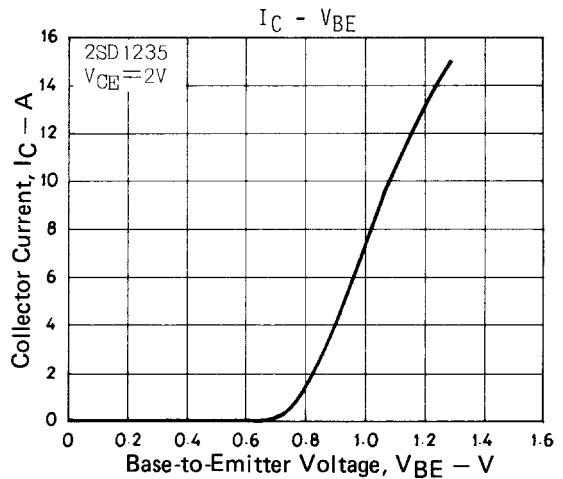
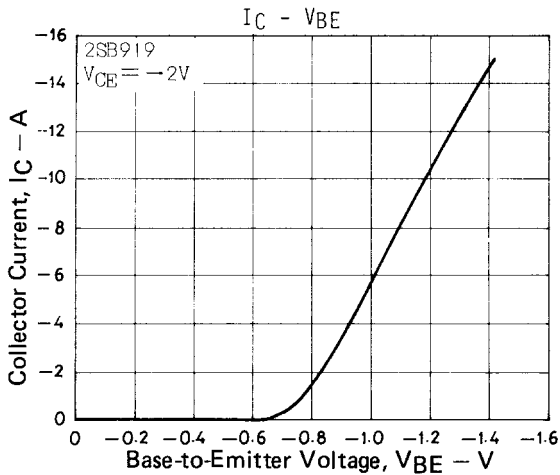
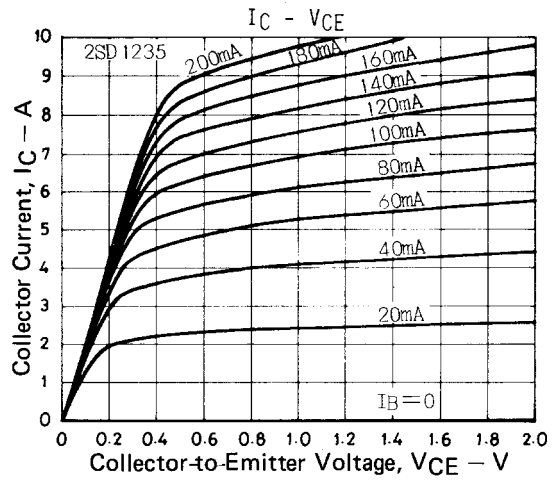
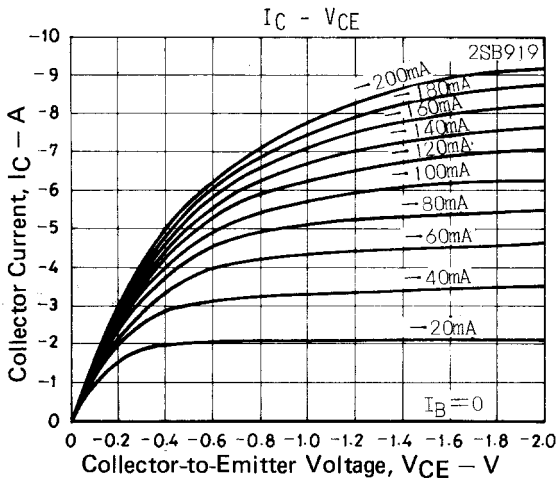
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Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C=(-)3A, I_B=(-)0.15A$			0.4	V
					(-0.5)	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C=(-)1mA, I_E=0$	(-60)			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C=(-)1mA, R_{BE}=\infty$	(-30)			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E=(-)1mA, I_C=0$	(-6)			V
Turn-ON Time	t_{on}	See specified Test Circuit		0.1		μs
Storage Time	t_{stg}	See specified Test Circuit		(0.2)		μs
				0.5		μs
Fall Time	t_f	See specified Test Circuit		0.03		μs

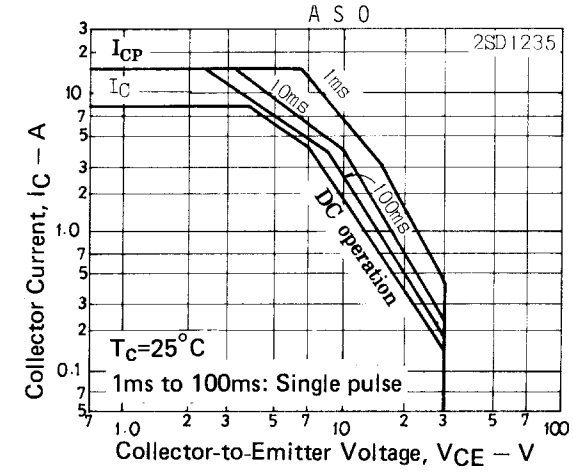
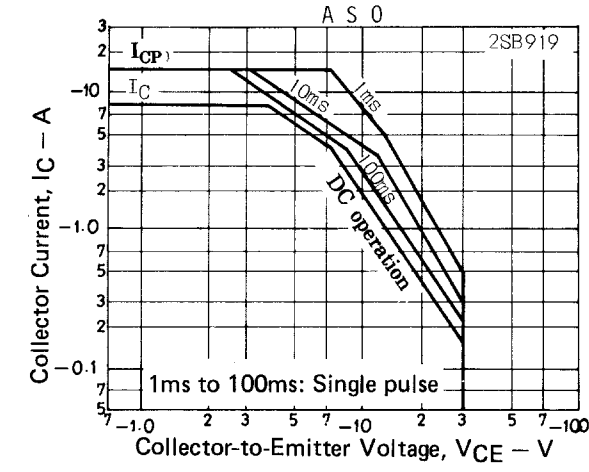
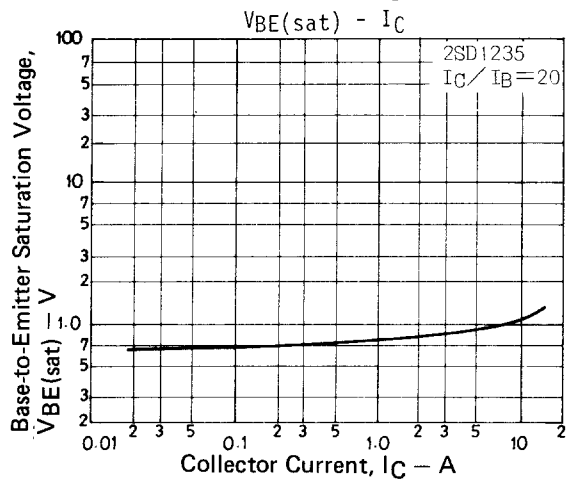
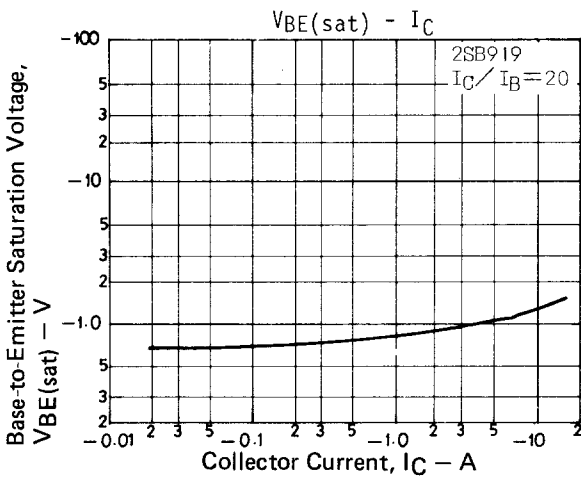
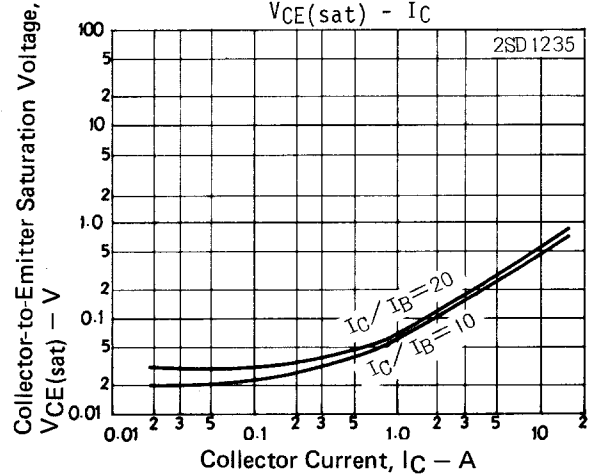
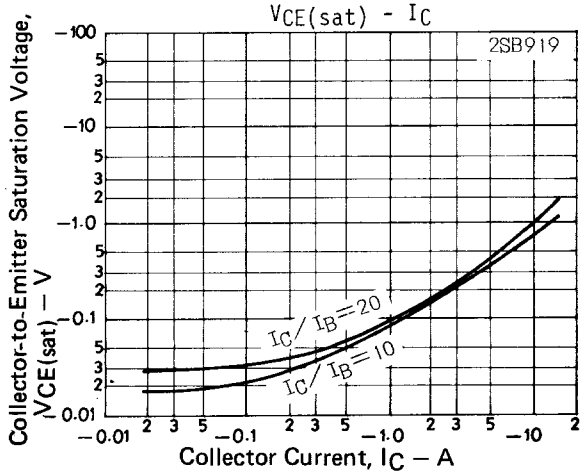
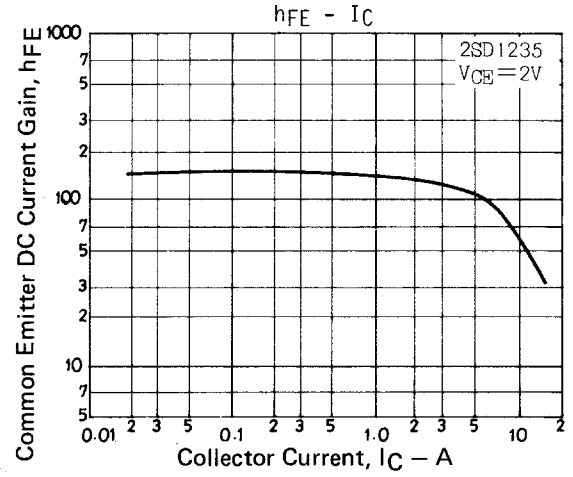
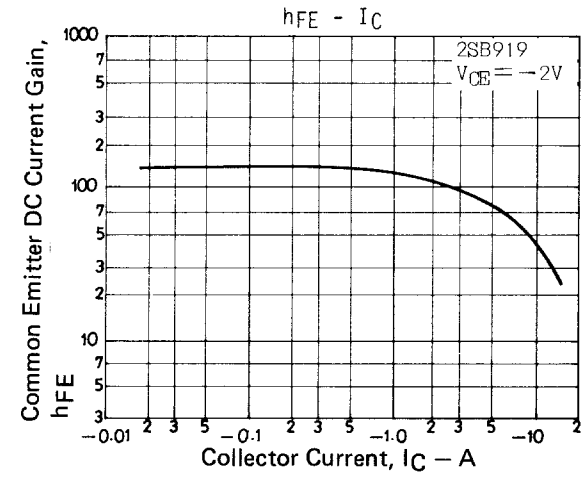
Switching Time Test Circuit

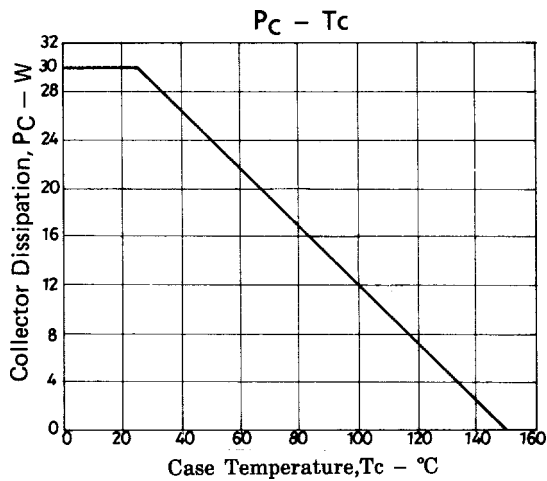


(For PNP, the polarity is reversed)
 Unit (resistance : Ω , capacitance : F)



2SB919/2SD1235





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